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INFO	INFORMATION DISCLOSURE			Application Number	10/804,629	1
	STATEMENT BY APPLICANT		Filing Date	March 19, 2004		
SIA			First Named Inventor Lucey et al.			
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			Examiner Name	To Be Assigned NAUARIO-5	WALLOZ	
Sheet	1	of	3	Attorney Docket Number	19226/2291 (R-5824, R-5875, R-5881)	

			U.S. PATENT DO	CUMENTS	
Examiner Initials	Cite No. ¹	U.S. Patent Document Number - Kind Code ³ (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Peges, Cohumns, Lines, Where Relevant Passages or Relevant Figures Appear
	1	US-2003/0097976	05/29/2003	Zehnder et al.	
	2	US-5,474,591	12/12/1995	Wells et al.	
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Examiner Initials	Cite No. 1	Foreign Patent Document	Publication Date	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant	
		Country Code ³ Number ⁴ (if known)	MM-DD-YYYY		Figures Appear	Τ⁴
d	11	WO 02/25745	03/28/2002	WIPO		
1	12	WO 02/29140	04/11/2002	WIPO		
7	13	WO 03/012006	02/13/2003	WIPO		
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Substitute for form 1449B/PTO		Complete if Known				
INFORMATION DISCLOSURE			LOSLIRE	Application Number	10/804,629	
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SIA	STATEMENT BY APPLICANT (use as many sheets as necessary)		First Named Inventor	Lucey et al.		
			Group Art Unit	1621		
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Sheet	2	of	3	Attorney Docket Number	19226/2291 (R-5824, R-5875, R-5881)	

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		OTHER PRIOR ART – NON PATENT LITERATURE DOCUMENTS	
Examiner Initials	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.)., date, page(s), volume-issue number(s), publisher, city and/or country where published.	T²
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Under the Paperwork Reduction Act of 1995, no persons are required to respond to a collection of information unless it contains a valid OMB control number. Complete if Known Substitute for form 1449B/PTO 10/804,629 **Application Number** INFORMATION DISCLOSURE March 19, 2004 Filing Date STATEMENT BY APPLICANT First Named Inventor Lucey et al. (use as many sheets as necessary) 1621 Group Art Unit To Be Assigned NAVAKIN GENTALEZ **Examiner Name** Attorney Docket Number Sheet 3 19226/2291 (R-5824, R-5875, R-5881)

Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.)., date, page(s), volume-issue number(s), publisher, city and/or country where published. Maury et al., "Raman Spectroscopy Characterization of Polycrystalline GaP Thin Films Grown By MO-CVD Process Using [Et ₂ Ga –PEt ₂] ₃ as Only Source," J. Phys. (Paris), 43:CI-347-CI-352 (1982) Maury et al., "Synthesis and Characterization of Diethylphosphino Ga(III) and In(III) Complexes with Covalent Metal-Phosphorus Bonds," Polyhedron, 3:581-584 (1984) Storr et al., "Cyclic Imino Derivatives of Aluminium, Gallium, and Indium Dialkyls," J. Chem. Soc., pp.3850-3854 (1971) Storr, "Trimeric Methylaminogallane, (MeNHGaH ₂) ₃ and Related Compounds," J. Chem. Soc., pp.2605-2608 (1968) Beachley et al., "Use of Me ₂ Ga(C ₅ H ₅) To Prepare (Me ₂ GaERR')n (E = N, P) at or Below Room Temperature and the Crystal and Molecular Structure of [Me ₂ GaP(Me)(Ph)] ₃ ," Organometallics, 12:1976-1980 (1993) Beachley et al., "Cyclopentadiene Elimination Reaction as a Route to Bis(neopentyl)gallium Phosphides. Crystal and Molecular Structures of [(Me ₃ CCH ₂) ₂ and	T ²
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	1	US-2002/0066401 A1	06-06-2002	Peng et al.	
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